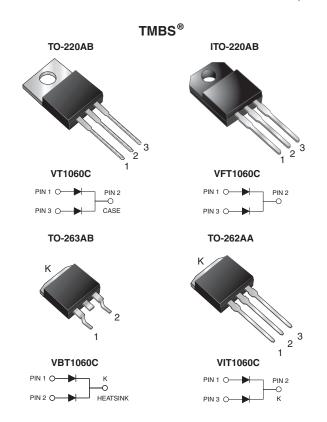
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Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.39 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 5 A					
$V_{RRM}$	60 V					
I <sub>FSM</sub>	100 A					
V <sub>F</sub> at I <sub>F</sub> = 5.0 A	0.50 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA					
Circuit configuration	Common cathode					

### **FEATURES**

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

· High efficiency operation



 Meets MSL level 1, per J-STD-020, Rol-LF maximum peak of 245 °C (for TO-263AB compul package)

 Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)

 Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, TO-263AB and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)									
PARAMETER			VT1060C	VFT1060C	VBT1060C	VIT1060C	UNIT		
Maximum repetitive peak reverse voltage	Maximum repetitive peak reverse voltage			60					
Maximum average forward rectified current (fig. 1)	per device	1	10						
Maximum average forward rectilled current (fig. 1)	per diode	I <sub>F(AV)</sub>	5						
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	100						
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH			65				mJ		
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C			1.0			Α			
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500				V		
Operating junction and storage temperature range			-55 to +150				°C		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode (1)	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	0.49	-	V		
	$I_F = 5.0 \text{ A}$			0.58	0.70			
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.39	-			
	I <sub>F</sub> = 5.0 A			0.50	0.60			
Reverse current per diode (2)	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub>	-	700	μΑ		
	$v_R = 60 \text{ V}$ $T_A = 12$	T <sub>A</sub> = 125 °C		6.9	25	mA		

### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER		SYMBOL	VT1060C	VFT1060C	VBT1060C	VIT1060C	UNIT
Typical thormal registance	per diode	$R_{ hetaJC}$	3.5	6.5	3.5	3.5	°C/W
Typical thermal resistance	per device		2.5	5.0	2.5	2.5	C/VV

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT1060C-E3/4W	1.87	4W	50/tube	Tube			
ITO-220AB	VFT1060C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VBT1060C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT1060CE3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT1060C-E3/4W	1.45	4W	50/tube	Tube			

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

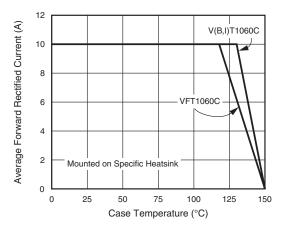


Fig. 1 - Maximum Forward Current Derating Curve

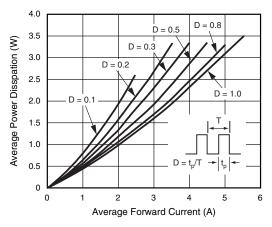


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

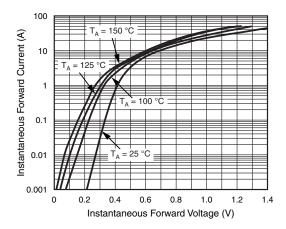


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

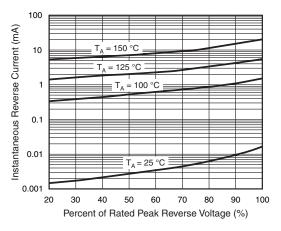


Fig. 4 - Typical Reverse Characteristics Per Diode

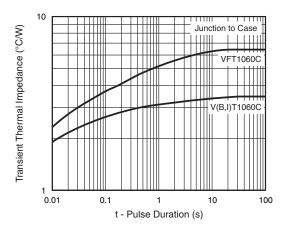


Fig. 5 - Typical Transient Thermal Impedance Per Diode

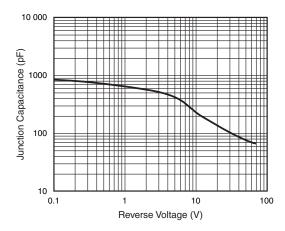
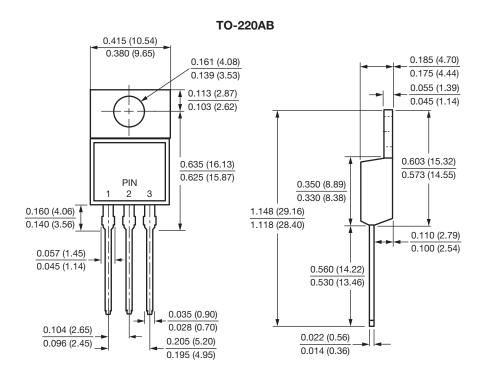


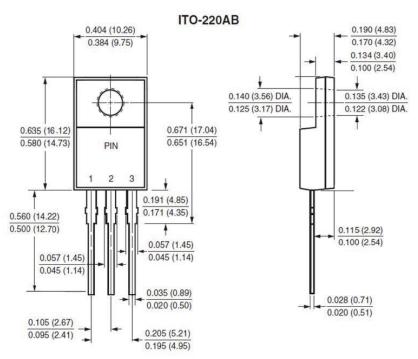
Fig. 6 - Typical Junction Capacitance Per Diode

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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

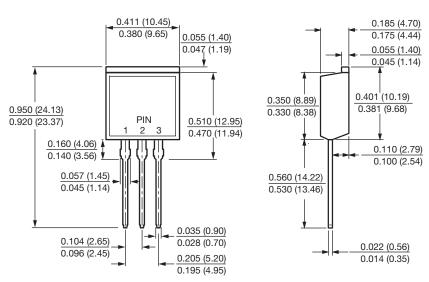
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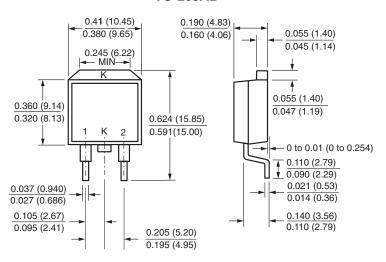


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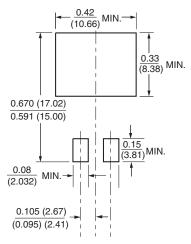
### **TO-262AA**



### **TO-263AB**



### **Mounting Pad Layout**





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